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Advanced Photonix, Inc. PDB-C120-L

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



Distributor of Advanced Photonix, Inc. : Excellent Integrated System Limited Datasheet of PDB-C120-L - PHOTODIODE BLUE 0.073MM SQ TO-46 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive DETECTORS INC. Type PDB-C120L PACKAGE DIMENSIONS INCH [mm] PACKAGE DIMENSIONS INCH [mm]



45 0.50 [12.7] MIN 0.040 0.145 [3.68] 0.189 [4.80] 0.029 [0.74] Ø0.019 [0.48] Ø0.016 [0.41] WIRE BOND 738/////// Ø0.195 [4.95 Ø0.178 [4.52 0.100 [2.54] 7777 17777 CATHODE & CASE PHOTODIODE CHIP Ø0.212 [5.38] LENS CAP (WELDED) Ø0.209 [5.31] 0.025 [0.64]

HEADER

FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The **PDB-C120L** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-46 metal can with a glass lens cap.

0.027 [0.69]

ACTIVE AREA = 0.073 mm^2

SQUARE Ø0.012 [Ø0.30] ACTIVE AREA

APPLICATIONS

0.022 [0.56]

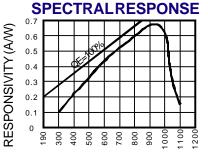
• Fiber optic

TO-46 HERMETIC CAN PACKAGE

- Laser detection
- Light demodulation
- Matched to I.R. LEDs

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		200	V
T _{STG}	Storage Temperature	-65	+150	°C
T _o	Operating Temperature Range	-55	+125	°C
T _s	Soldering Temperature*		+240	°C
Ι	Light Current		500	mA



WAVELENGTH(nm)

*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS			
l _{sc}	Short Circuit Current	H = 100 fc, 2850 K	1.2	1.5		μA			
I _D	Dark Current	H = 0, V _R = 10 V		0.5	2.0	nA			
R _{SH}	Shunt Resistance	$H = 0, V_{R} = 10 \text{ mV}$	400	500		MΩ			
TCR _{SH}	RSH Temp. Coefficient	$H = 0, V_{R} = 10 \text{ mV}$		-8		% / °C			
CJ	Junction Capacitance	H = 0, V _R = 10 V**		1		рF			
λrange	Spectral Application Range	Spot Scan	350		1100	nm			
λρ	Spectral Response - Peak	Spot Scan		950		nm			
V _{BR}	Breakdown Voltage	I = 10 µµA	100	150		V			
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		9.0x10 ⁻¹⁵		W/√ ^{Hz}			
tr	Response Time	$RL = 1 K\Omega V_R = 50 V$		1.0		nS			

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f=1MHz [FORM NO. 100-PDB-C120L REV A]